

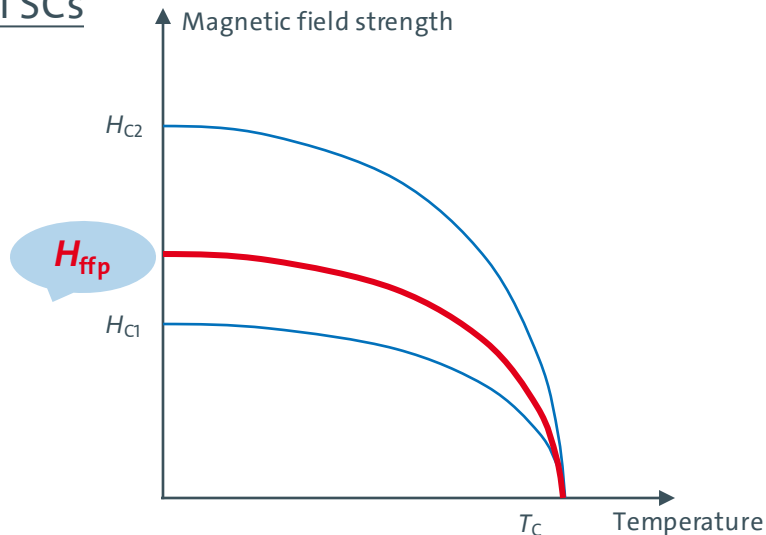
Beyond Bulk Niobium R&D: SIS Multilayer Studies for a New Generation of SRF Cavities

Lea Preece - on behalf of the SRF R&D Team Hamburg
11. Annual MT Meeting, 3.-6. Nov. 2025

Superconductivity in Particle Accelerators



Type II SCs



Niobium as material of choice for SRF cavities

- ✓ Highest known T_C of **9.27 K**
- ✓ Highest known H_{C1} of **180 mT**

Upper limit for rf vortex
penetration is even higher:

Superheating field

$H_{sh,Nb} \sim 200 \text{ to } 250 \text{ mT}$

Limiting Performance Factors

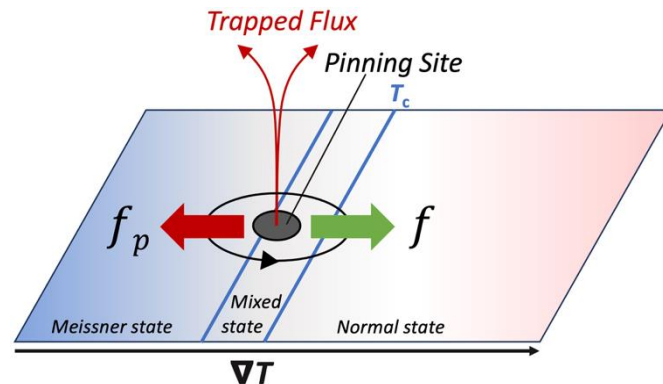
Surface Resistance

$$R_S = \underbrace{A \frac{\omega^2}{T} \exp\left(-\frac{\Delta}{k_B T}\right)}_{R_{BCS}} + R_{res}$$

R_{BCS} vanishes for $T \rightarrow 0$ K

Everything *except* R_{BCS}

- Weakly coupled grain boundaries, surface oxides etc.
- Trapped magnetic flux



Quality Factor

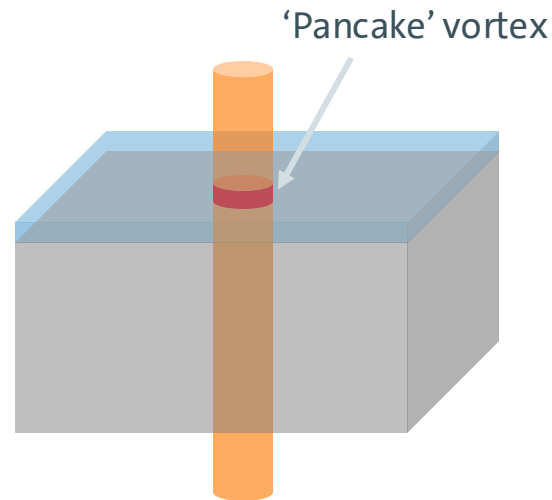
$$Q_0 \sim \frac{1}{R_S}$$

- Magnetic Quenching when $H_{\text{applied}} > H_{C1}$
- Dissipation becomes unmanagable!

**E_{acc} is limited by dissipation
because of high surface
magnetic fields!**

Thin Films and Pancake Vortices

- Vortices energetically suppressed in SC thin film
 - Thinner than the London penetration depth
 $d < \lambda_{L, \text{NbTiN}} \text{ (~ nm)}$
- Coat inner cavity surface with higher- T_c superconductor
NbTiN $T_c = 17.8 \text{ K}$
- **Superconductor-Insulator-Superconductor (SIS)** multilayers
 - Insulator as vortex barrier

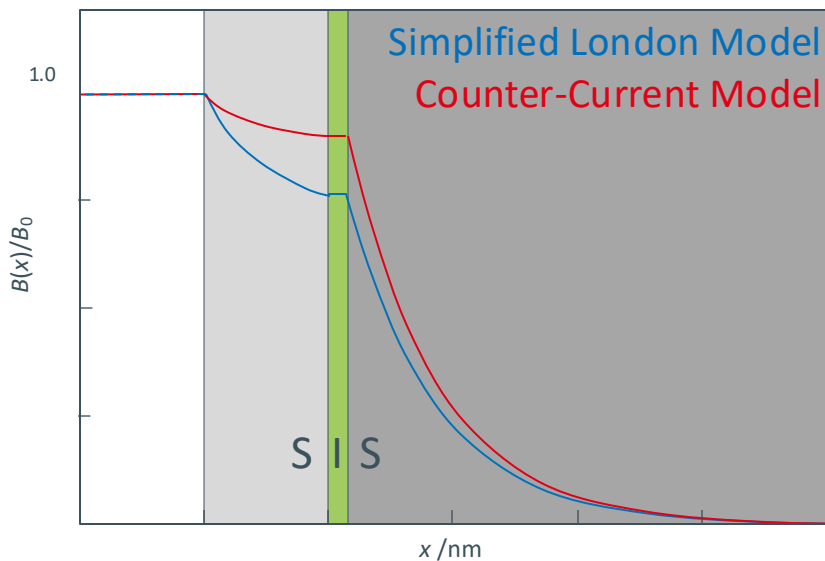


Vortex dissipation becomes energetically unfavourable

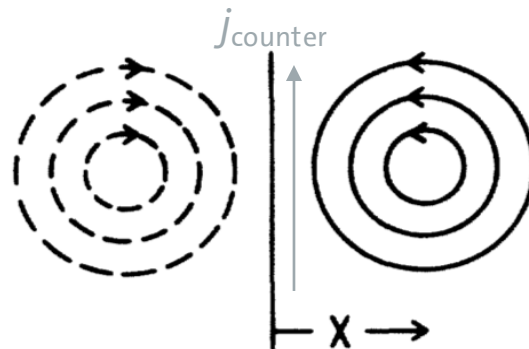
*For more detail see:
A. Gurevich, APL 88 (2006)*

Counter Currents at the Interfaces

- Vortex penetration shifts to higher H_{ffp} through “**counter currents**” at interfaces



Bean-Livingston Barrier

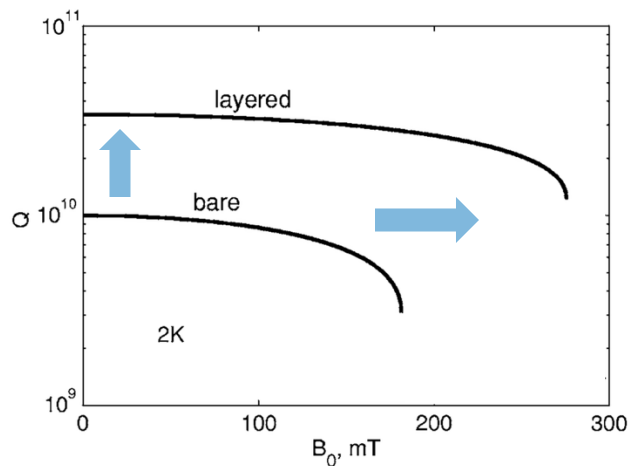


For more detail see:
 T. Kubo, SUST 30 (2017)

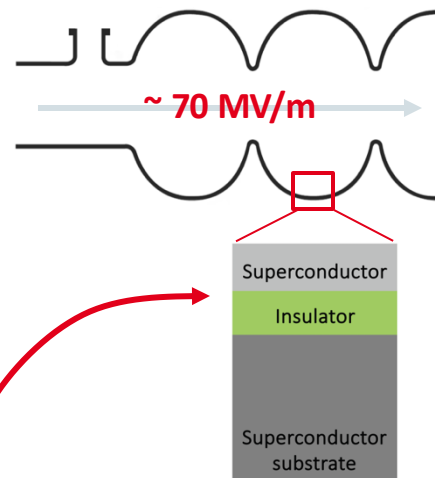
The Need for SIS Multilayers in SRF

SRF cavities approach thermodynamic limit of niobium

Superconductor-Insulator-Superconductor multilayer theory shows **potential to enhance E_{acc}** and achieve **lower rf losses**



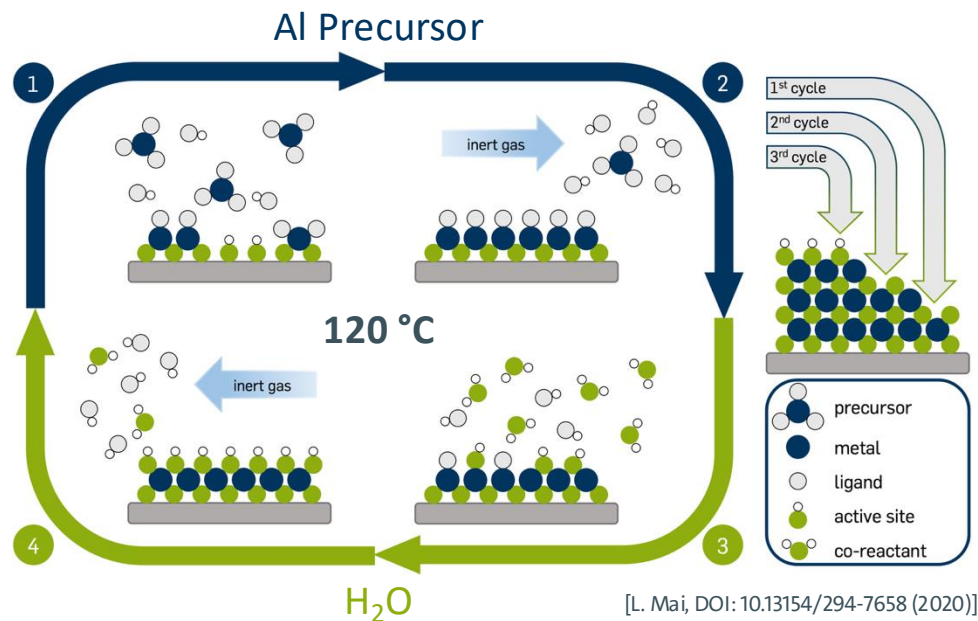
[A. Gurevich, Appl. Phys. Lett. 88, 012511 (2006)]



**Realization of thin multilayer coating
on the inner
cavity surface is challenging!**

ALD is the Key to Success

Thermal Atomic Layer Deposition



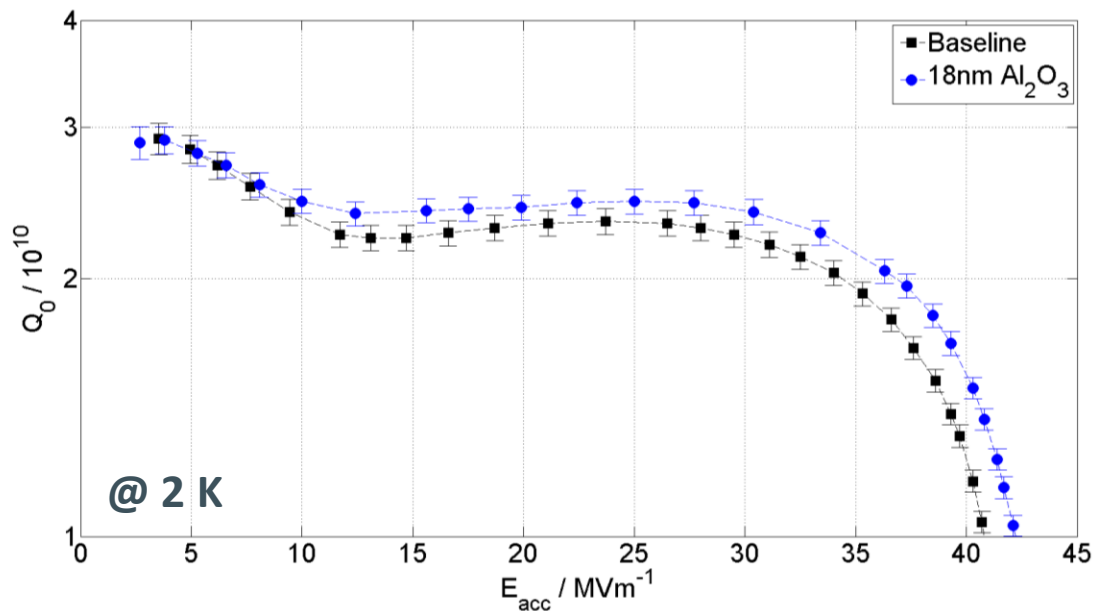
⇒ forms Al_2O_3 atomic layers

- ➡ Uniform deposition of high quality and high conformality
- ➡ Surface-controlled process
- ➡ Sub-nm thickness control

Thermal ALD System at University of Hamburg



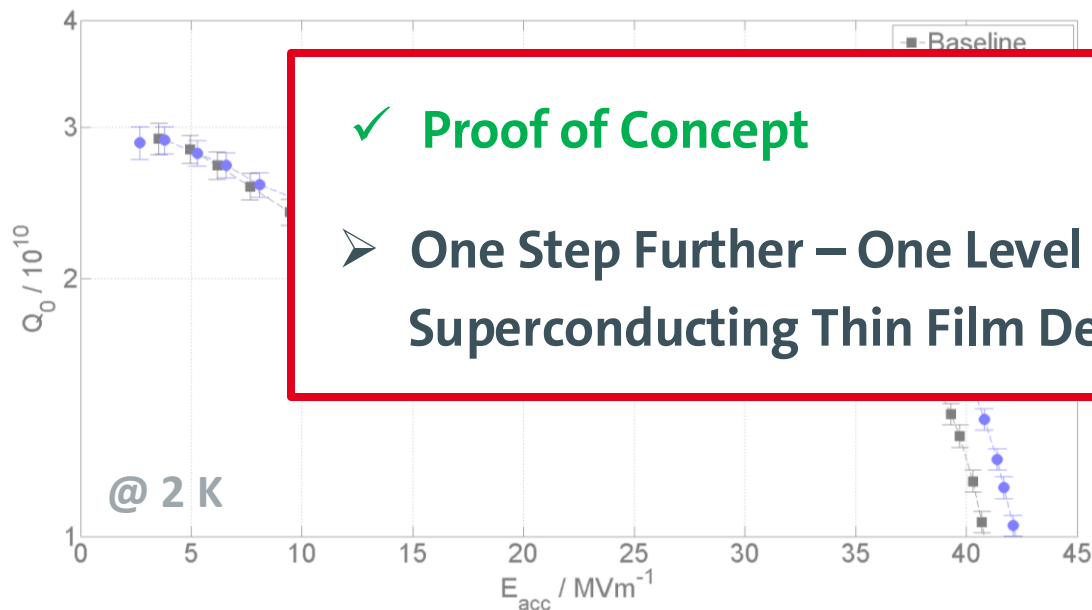
Thermal ALD coating on a 1.3 GHz cavity



- ✓ Uniform and conformal surface coverage through ALD
- ✓ Preserved cavity performance

[Wenskat, M., Deyu. G. et al., Supercond. Sci. Technol. 36.1 (2022): 015010.E.]

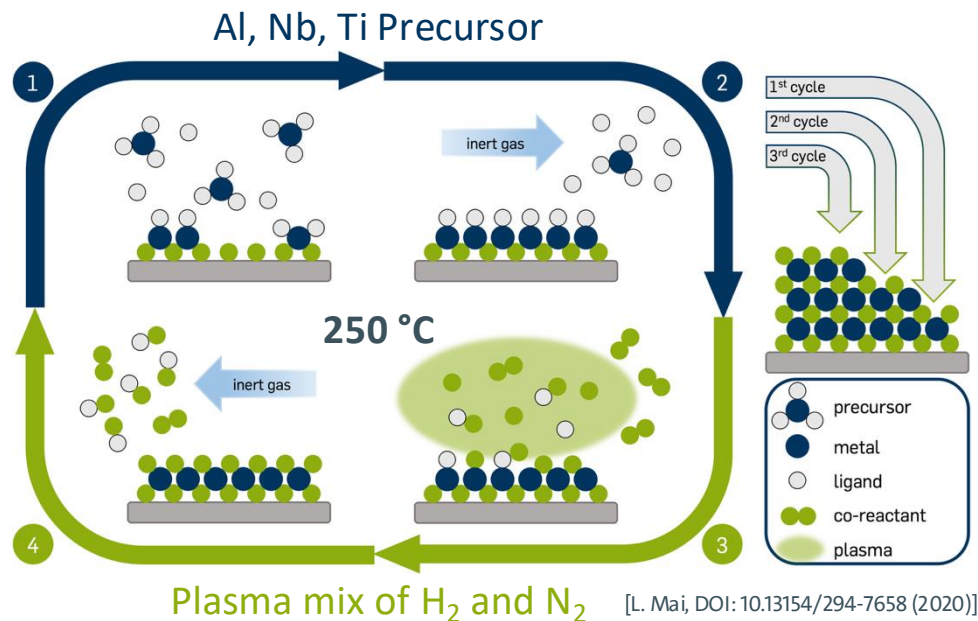
Thermal ALD coating on a 1.3 GHz cavity



[Wenskat, M., Deyu. G. et al., Supercond. Sci. Technol. 36.1 (2022): 015010.E.]

Benefits of PEALD for SIS Multilayers

Plasma-Enhanced Atomic Layer Deposition



⇒ forms AlN, $\text{TiN} + \text{NbN} = \text{NbTiN}$

- ✓ Lower deposition temperature
- ✓ **No** acidic chemicals
- ✓ Higher crystalline order expected
- ✓ High precision thickness control

Plasma-Enhanced ALD System at University of Hamburg



Sample
deposition
device...

... a cavity
will not fit
in there!

Comprehensive PEALD-Coated Sample Study

Deposition of

☞ NbTiN only (**SS Sample**) ~ 60 nm

☞ AlN + NbTiN (**SIS Sample**) ~ (15+60) nm

On planar substrates:



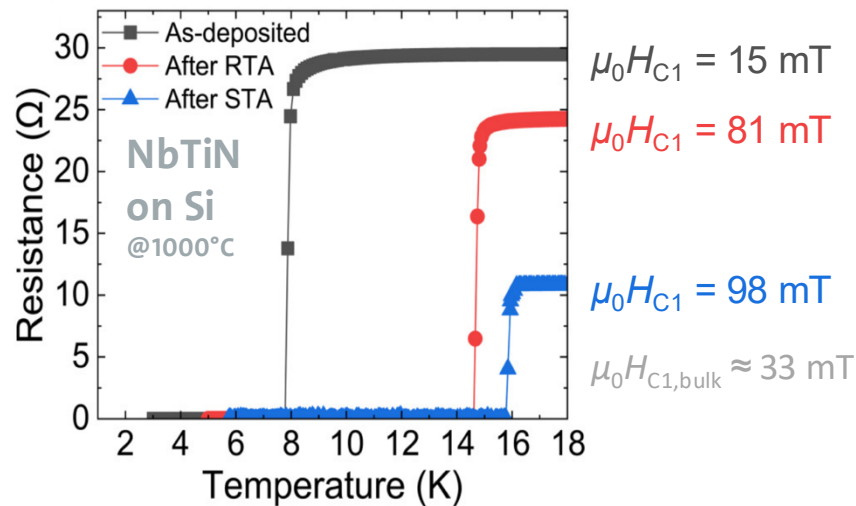
Si wafer



Nb substrate

*Standard cavity
surface preparation*

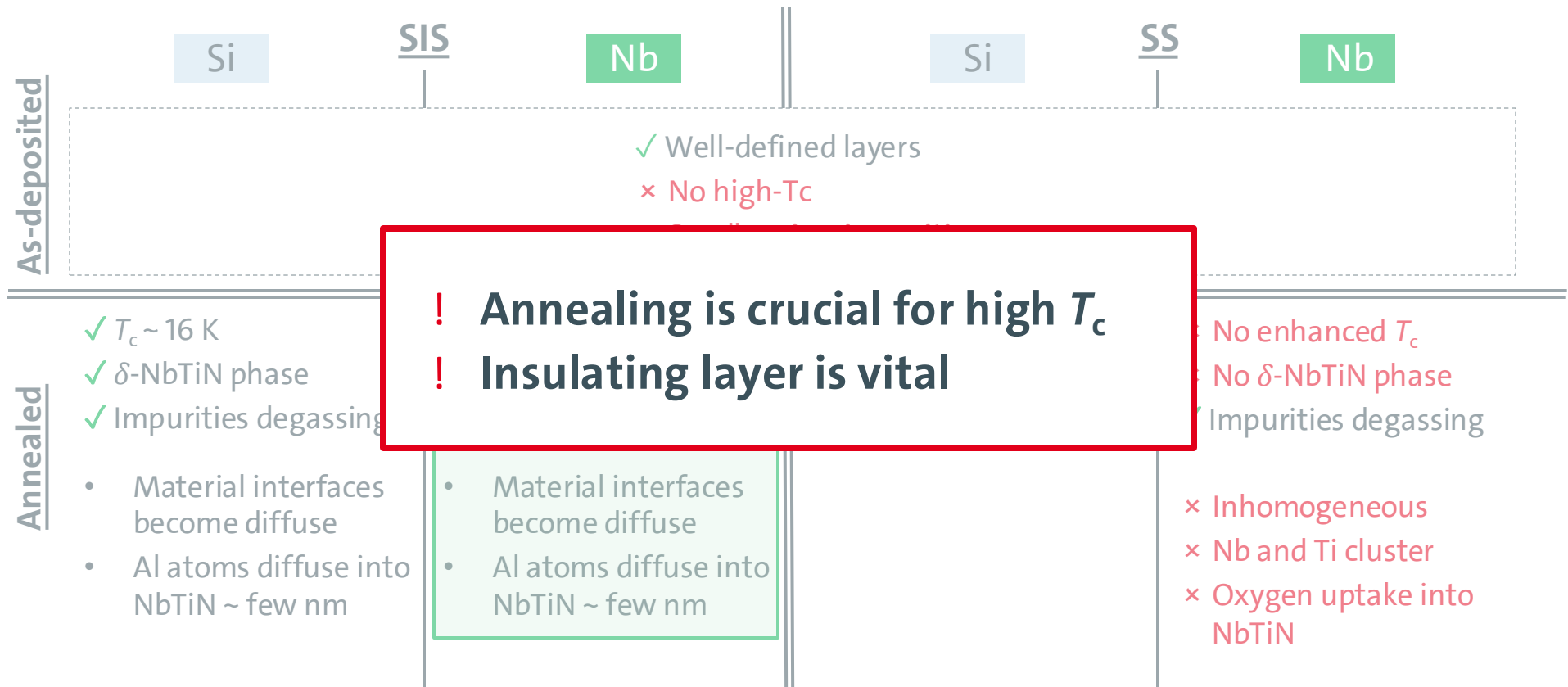
1 hour **high temperature annealing** to enhance superconducting material properties



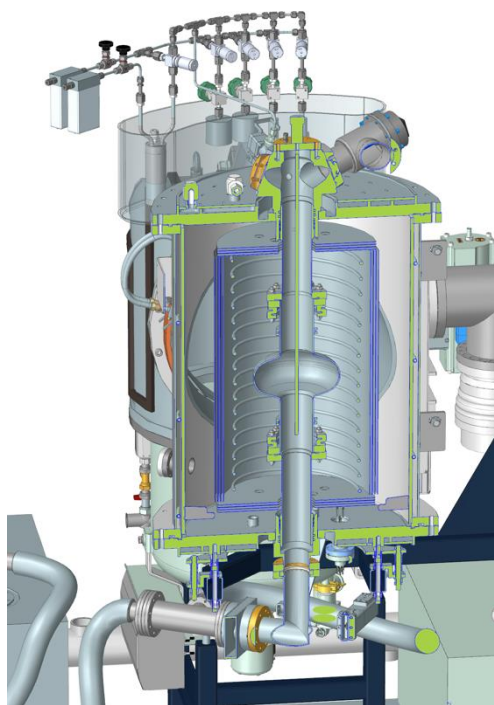
[González.I. et al., J. Appl. Phys. 134, 159902 (2023), 035301 (2023)]

What have we learned about multilayers so far?

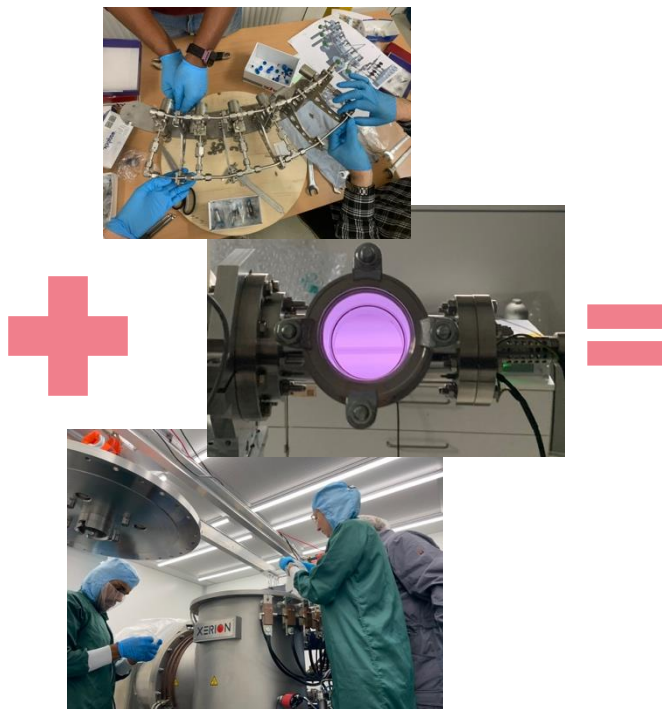
	As-deposited					
	Si	SIS	Nb	Si	SS	Nb
	✓ Well-defined layers × No high-T_c × Small grains, impurities					
Annealed	✓ $T_c \sim 16$ K ✓ δ-NbTiN phase ✓ Impurities degassing • Material interfaces become diffuse • Al atoms diffuse into NbTiN ~ few nm	✓ $T_c \sim 14$ K ✓ δ-NbTiN phase ✓ Impurities degassing • Material interfaces become diffuse • Al atoms diffuse into NbTiN ~ few nm		✓ $T_c \sim 16$ K ✓ δ-NbTiN phase ✓ Impurities degassing	× No enhanced T_c × No δ-NbTiN phase ✓ Impurities degassing × Inhomogeneous × Nb and Ti cluster × Oxygen uptake into NbTiN	



New PEALD SIS Cavity-Coating System



A sophisticated design...

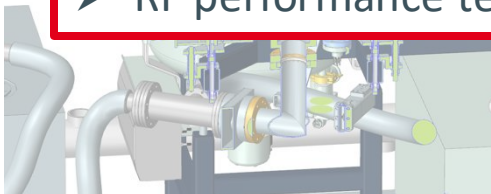


A lot of hard work by a great team!



... becomes reality!

New PEALD SIS Cavity-Coating System

- 
- 
- 
- 
- Scaling-up sample deposition parameters to **single-cell cavity** deposition
 - Coating **single-cell cavities** with AlN-NbTiN SIS multilayers
 - RF performance tests on the **coated cavities**



A sophisticated design...

A lot of hard work by a great team!

... becomes reality!

- ✓ **PEALD** is the **key technique** for **SIS cavity-coating**
- ✓ Expertise for successful PEALD coating and process optimisation
- ✓ Vital importance of thermal annealing and insulating layer proven
- ✓ Further investigation ongoing

Operation of the new Cavity-Coating System will begin soon!

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